

Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coefficient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior
- Increased Creepage / Clearance + HV-H3TRB Rugged

Applications

- Battery Chargers
- Solar & Renewable Energy Power Conversion
- Industrial Power Supplies
- Boost Diodes in PFC & DC-DC





T0247-2L Package



Part Number	Package	Marking
HC4D40120H	TO247-2L	HC4D40120H

Maximum Ratings($T_c = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Value	Unit	Test Conditions	Note	
Repetitive Peak Reverse Voltage	V _{RRM}	1200	N			
DC Blocking Voltage	V _{DC}	1200	V			
		128		T _j = 25 °C		
Continuous Forward Current	I _F	88	A	T _j = 100 °C	Fig. 3	
		41		T _j = 155 °C		
Repetitive Peak Forward Surge	I _{FRM}	161		$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Pulse}$		
Current		91		$T_c = 110 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Pulse}$		
Non-Repetitive Forward Surge		247		$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Pulse}$		
Current	I _{FSM}	245		$T_c = 110 \text{ °C}, t_p = 10 \text{ ms}, \text{Half Sine Pulse}$		
Power Dissipation	P _{tot}	667	W	$T_c = 25 \text{ °C}$	- Fig. 4	
		289		T _c = 110 °C		
i²t Value	∫ i²t	305	A ² s	$T_c = 25 \text{ °C}, t_p = 10 \text{ ms}$		
		300		$T_c = 110 \text{ °C}, t_p = 10 \text{ ms}$		



Electrical Characteristics

Parameter	Symbol	Тур.	Max.	Units	Test Conditions	Note	
Forward Voltage	V _F	1.5	1.8	V	I _F = 40 A, T _J = 25 °C	Fig. 1	
		2.2	3		I _F = 40 A, T _J = 175 °C		
Reverse Current	I _R	45	300	μΑ	V _R = 1200 V, T _J = 25 °C	Fig. 2	
		75	500		V _R = 1200 V, T _J = 175 °C		
Total Capacitive Charge	Q _c	167		nC	$V_{R} = 800 \text{ V}, \text{ T}_{J} = 25 \text{ °C}$	Fig. 5	
	С	2,809		pF	$V_{R} = 0 V, T_{J} = 25 °C, f = 1 MHz$		
Total Capacitance		174			$V_{R} = 400 \text{ V}, \text{ T}_{J} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$	Fig. 6	
		145			$V_{R} = 800 \text{ V}, \text{ T}_{J} = 25 \text{ °C}, \text{ f} = 1 \text{ MHz}$		
Capacitance Stored Energy	E _c	36		μJ	V _R =800 V	Fig. 7	

Note:

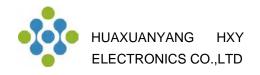
SiC Schottky Diodes are majority carrier devices, so there is no reverse recovery charge.

Thermal & Mechanical Characteristics

Parameter	Symbol	Value	Units	Note
Thermal Resistance, Junction to Case (Typ.)	R _{θ, JC}	0.225	°C / W	
Operating Junction & Storage Temperature	T _J , T _{stg}	-55 to +175	°C	Fig. 8
Maximum Processing Temperature	T _{PROC}	325		10 min. Maximum

Electrostatic Discharge (ESD) Classifications

Parameter	Symbol	Value
Human Body Model	НВМ	Class 3B (≥ 8000 V)
Charge Device Model	CDM	Class C3 (≥ 1000 V)



Typical Performance

Figure 1. Forward Characteristics

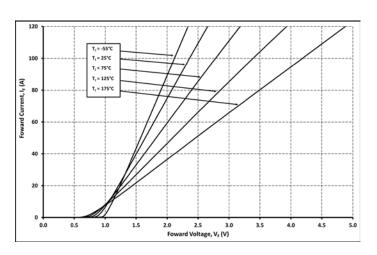
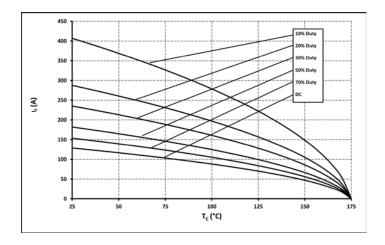
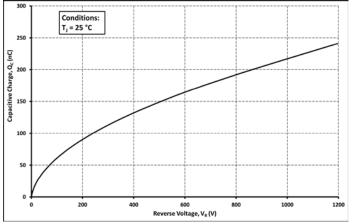


Figure 3. Current Derating







600 500 400 T; = 175 °C 300 T, = 125 *C T, = 75 °C 200 T, = 25 °C T, = -55 °C 100 1800 0 200 400 600 800 1000 1200 1400 1600 Reverse Voltage, V_R (V)

Reverse Leakage Current, I_{RR} (uA)

Figure 2. Reverse Characteristics

Figure 4. Power Derating

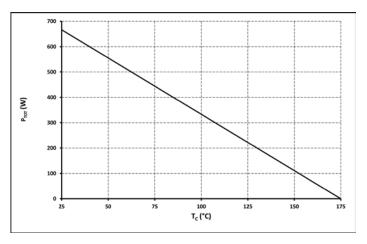
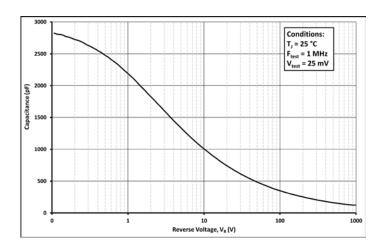


Figure 6. Capacitance vs. Reverse Voltage





Typical Performance

Figure 7. Capacitance Stored Energy

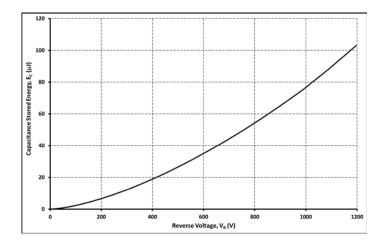
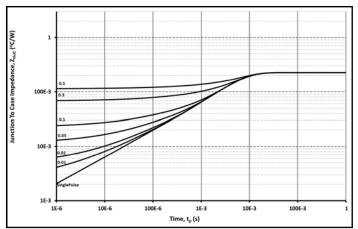
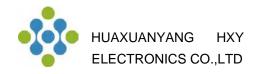


Figure 8. Transient Thermal Impedance

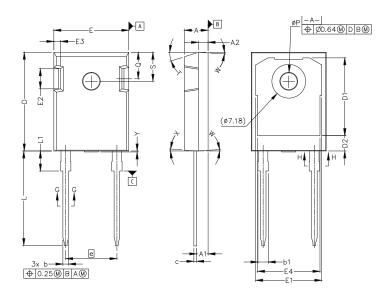




Package Dimensions

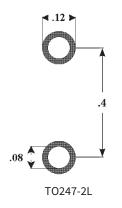
Package: TO247-2L

All dimensions in mm.

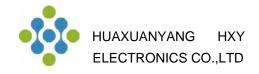


			INCH	50	
SYM	MILLIM	MILLIMETERS		ES	
3110	MIN	MAX	MIN	MAX	
А	4.83	5.21	.190	.205	
Al	2.29	2.54	.090	.100	
A2	1.91	2.16	.075	.085	
b'	1.07	1.28	.042	.050	
b	1.07	1.33	.042	.052	
b1	1.91	2.41	.075	.095	
b2	1.91	2.16	.075	.085	
c'	0.55	0.65	.022	.026	
с	0.55	0.68	.022	.027	
D	20.80	21.10	.819	.831	
D1	16.25	17.35	.640	.683	
D2	2.86	3.16	.112	.124	
Е	15.75	16.13	.620	.635	
E1	13.10	14.15	.516	.557	
E2	3.68	5.10	.145	.201	
E3	1.00	1.90	.039	.075	
E4	12.38	13.43	.487	.529	
e	10.88	BSC	.428 BSC		
L	19.81	20.32	.780	.800	
Ll	4.10	4.40	.161	.173	
ØΡ	3.51	3.65	.138	.144	
Q	5.49	6.00	.216	.236	
S	6.04	6.30	.238	.248	
Т	17.5° REF.				
W	3.5° REF.				
Х	4° REF.				
Y	0	0.50	0	0.020	

Recommended Solder Pad Layout



all units are in inches



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